

P-Channel Enhancement Mode MOSFET

Feature

 $\bullet \quad \text{-30V/-4.0A}, \quad \text{Rds(on) =65m} \Omega(\text{MAX}) \text{ @Vgs = -10V}.$

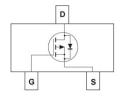
$$\begin{split} &R{\rm DS(ON)} = 80m\Omega(MAX) \ \ \text{@VGS} = -4.5V. \\ &R{\rm DS(ON)} = 120m\Omega(MAX) \ \ \text{@VGS} = -2.5V. \end{split}$$

• Super High dense cell design for extremely low RDS(ON)

- Reliable and Rugged
- SOT-23 for Surface Mount Package



SOT-23



Applications

Power Management

Portable Equipment and Battery Powered Systems.

Absolute Maximum Ratings TA=25 °C Unless Otherwise noted

Parameter	Symbol	Limit	Units	
Drain-Source Voltage	V_{DS}	-30	V	
Gate-Source Voltage	V_{GS}	±12	V	
Drain Current-Continuous	I_D	-4.0	A	

Electrical Characteristics TA=25°C Unless Otherwise noted

Parameter	Symbol	Test Conditions	Min	Тур.	Max	Units	
Off Characteristics							
Drain to Source Breakdown Voltage	BVDSS	VGS=0V, ID=-250μA	-30	-	-	V	
Zero-Gate Voltage Drain Current	IDSS	VDS=-24V, VGS=0V	-	-	-1	μΑ	
Gate Body Leakage Current, Forward	IGSSF	VGS=12V, VDS=0V	-	-	100	nA	
Gate Body Leakage Current, Reverse	IGSSR	VGS=-12V, VDS=0V	-	-	-100	nA	
On Characteristics			•		•		
Gate Threshold Voltage	VGS(th)	VGS= VDS, ID=-250μA	-0.7	-	-1.3	V	
Static Drain-source On-Resistance	RDS(ON)	VGS =-10V, ID =-4.0A	-	55	65	mΩ	
		VGS =-4.5V, ID =-4.0A	-	70	80	mΩ	
		VGS =-2.5V, ID =-1.0A	-	80	120	mΩ	
Drain-Source Diode Characteristics and Maximum Ratings							
Drain-Source Diode Forward Voltage	VSD	VGS =0V, IS=-1.0A			-1.0	V	

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Typical Characteristics

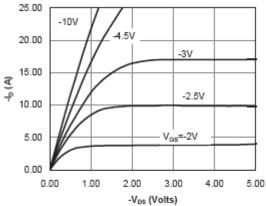


Fig 1: On-Region Characteristics

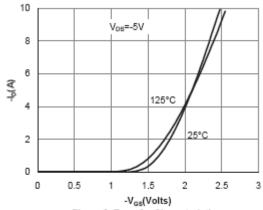


Figure 2: Transfer Characteristics

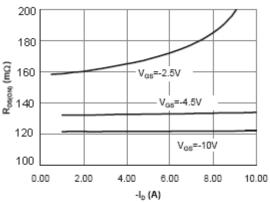
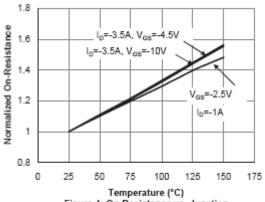


Figure 3: On-Resistance vs. Drain Current and Gate Voltage



Temperature (°C) Figure 4: On-Resistance vs. Junction Temperature

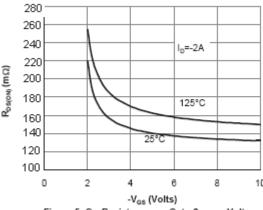


Figure 5: On-Resistance vs. Gate-Source Voltage

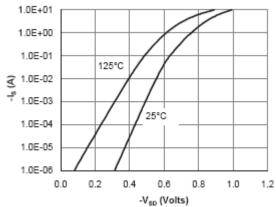
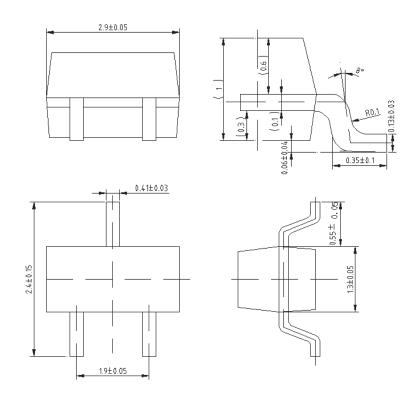


Figure 6: Body-Diode Characteristics



Package Outline Dimensions (UNIT: mm)

SOT-23



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